

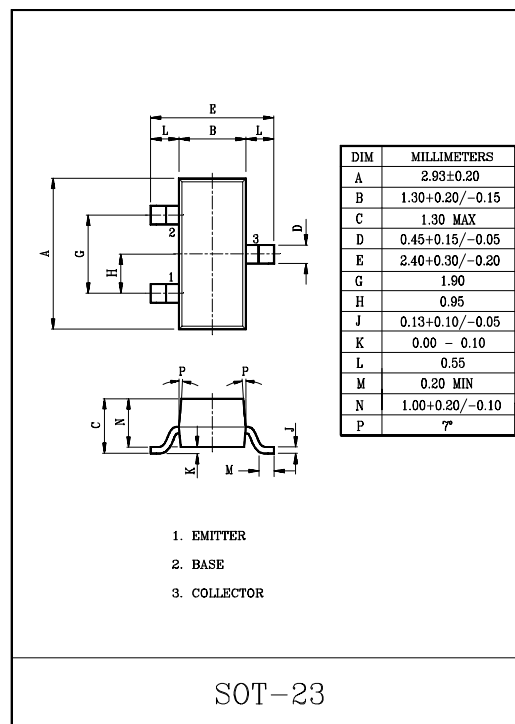
FOR MUTING AND SWITCHING APPLICATION.

FEATURES

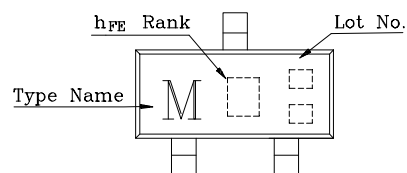
- High Emitter-Base Voltage : $V_{EBO}=25V(\text{Min.})$
- High Reverse h_{FE}
: Reverse $h_{FE}=150(\text{Typ.})$ ($V_{CE}=-2V$, $I_C=-2mA$)
- Low on Resistance : $R_{ON}=1\Omega(\text{Typ.})$, ($I_B=5mA$)

MAXIMUM RATINGS ($T_a=25^\circ C$)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	50	V
Collector-Emitter Voltage	V_{CEO}	20	V
Emitter-Base Voltage	V_{EBO}	25	V
Collector Current	I_C	300	mA
Base Current	I_B	60	mA
Collector Power Dissipation	P_C	150	mW
Junction Temperature	T_j	125	$^\circ C$
Storage Temperature Range	T_{stg}	$-55 \sim 125$	$^\circ C$



Marking



ELECTRICAL CHARACTERISTICS ($T_a=25^\circ C$)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB}=50V$, $I_E=0$	-	-	0.1	μA
Emitter Cut-off Current	I_{EBO}	$V_{EB}=25V$, $I_C=0$	-	-	0.1	μA
DC Current Gain (Note)	h_{FE}	$V_{CE}=2V$, $I_C=4mA$	200	-	1200	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=30mA$, $I_B=3mA$	-	0.042	0.3	V
Base-Emitter Voltage	V_{BE}	$V_{CE}=2V$, $I_C=4mA$	-	0.61	-	V
Transition Frequency	f_T	$V_{CE}=6V$, $I_C=4mA$	-	30	-	MHz
Collector Output Capacitance	C_{ob}	$V_{CB}=10V$, $I_E=0$, $f=1MHz$	-	4.8	7	pF
Switching Time	Turn-on Time		-	160	-	nS
	Storage Time		-	500	-	
	Fall Time		-	130	-	

Note : h_{FE} Classification A: 200~700 , B: 350~1200

